Dual 1.5MHz, 1A Synchronous Step-Down Converter

Features

- 1A Output Current on Each Channel
- 2.7V to 5.5V Input Voltage Range
- 1.5MHz Constant Frequency Operation
- Low Dropout Operation at 100% Duty Cycle
- Synchronous Topology
- 0.6V Low Reference Voltage
- Current Mode Operation
- Over-Temperature Protection
- Over-Current Protection
- Up to 94% Efficiency
- Internally Compensated
- Lead Free and Green Devices Available (RoHS Compliant)

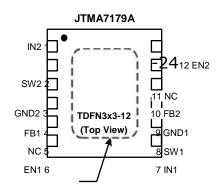
Applications

- TV Tuner/Box
- Portable Instrument

General Description

The JTMA7179A consists of two independent 1.5MHz constant frequency, current mode, and PWM step-down converters. Each converter integrates a main switch with a synchronous rectifier for high efficiency without an external Schottky diode. The JTMA7179A is ideal for powering portable equipment that runs from a single cell Lithium-lon (Li+) battery. Each converter can supply 1A of load current from a 2.7V to 5.5V input voltage. The output voltage can be regulated as low as 0.6V. The JTMA7179A can also run at 100% duty cycle for low dropout applications.

Pin Configuration



Exposed pad on backside

Ordering and Marking Information

JTMA7179A		Assembly Material Handling Code Temperature Range Package Code	Package Code QB: TDFN3x3-12 Temperature Range I: -40 to 85 C° Handling Code TR: Tape & Reel Assembly Material G: Halogen and Lead Free Device	
JTMA7179A QB:	JTMA 7179A XXXXX		XXXXX - Date Code	

Note: JIATAIMU lead-free products contain molding compounds/die attach materials and 100% matte tin plate termination finish; which are fully compliant with RoHS. JIATAIMU lead-free products meet or exceed the lead-free requirements of IPC/JEDEC J-STD-020D for MSL classification at lead-free peak reflow temperature. JIATAIMU defines "Green" to mean lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500ppm by weight).

JIATAIMU reserves the right to make changes to improve reliability or manufacturability without notice, and advise customers to obtain the latest version of relevant information to verify before placing orders.

Absolute Maximum Ratings (Note 1)

Symbol	Parameter	Rating	Unit
VIN1/IN2	Input Supply Voltage (IN1/IN2 to GND1/GND2)	-0.3 ~ 6	V
V _{FB1/FB2}	Voltage on FB1 and FB2 (FB1/FB2 to GND1/GND2)	-0.3 ~ VIN1/IN2+0.3	V
VEN1/EN2	Voltage on EN1 and EN2 (EN1/EN2 to GND1/GND2)	-0.3 ~ VIN1/IN2+0.3	V
Vsw1/sw2	Voltage on SW1 and SW2 (SW1/SW2 to GND1/GND2)	-0.3 ~ VIN1/IN2+0.3	V
ISW_PEAK	Peak SW Current	1.8	Α
P□	Maximum Power Dissipation (T _A =25°C)	2	W
Тл	Maximum Junction Temperature	150	°C
Тѕтс	Storage Temperature Range	-65 ~ 150	°C
Tsdr	Maximum Lead Soldering Temperature, 10 Seconds	260	°C

Note1: Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Thermal Characteristics

S	Symbol	Parameter	Typical Value	Unit
	\JA	Junction-to-Ambient Resistance in Free Air (Note 2) TDFN3x3-1	50	°C/W
	/ıc	Junction-to-Case Resistance in Free Air TDFN3x3-1	12	

Note 2: \\(\text{\text{A}}\) is measured on with the device mounted the PCB with top-layer pad of approximate 1" square of 1 oz copper.

Recommended Operating Conditions

Symbol	Parameter	Range	Unit
VIN1/IN2	Input Supply Voltage (IN1/IN2 to GND1/GND2)	2.7 ~ 5.5	V
R2/R4	Feedback Resistance (Note 3)	~ 300	k&
Іоит	Output Current	0 ~ 1	Α
TA	Operating Ambient Temperature	-40 ~ 85	°C
TJ	Operating Junction Temperature	-40 ~ 125	°C

Note 3: Please refer to the typical application circuit.

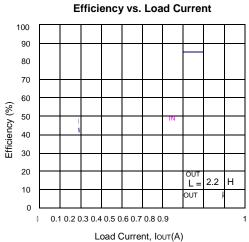
Electrical Characteristics

The denotes the specifications that apply over V_{IN} =3.6V and T_{A} =25°C, unless otherwise specifications.

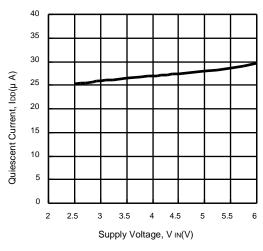
Symbol	Parameter	Test Conditions	JTMA7179A			Unit
Cymbol			Min.	Тур.	Max.	Oilit
VIN1/IN2	Each Converter Input Voltage Range		2.7	-	5.5	V
FB1/FB2	FB1/FB2 Input Current	V _{FB1/FB2} =0.6V	-30	-	30	nA
VREF1/REF2	Each Converter Reference Voltage	Iouт=0mA~1A	0.588	0.6	0.612	V
□VREF1/REF2	Each Converter Reference Voltage Line Regulation	-40°CδΤ _Α δ85 C °	-	0.04	-	%/V
Ірк	Each Converter Peak Inductor Current	V _{IN1/IN2} =3.3V, V _{FB} =0.5V or V _{OUT} =90%, Duty cycle < 35%	1.4	1.6	-	Α
	Each Converter Load Regulation	Iout=10mA~1A	ı	0.5	-	%
IDD	Each Converter Switching Current	V _{FB1/FB2} =0.6V, SW1/SW2 Floating	-	2	-	mA
Isp	Each Converter Quiescent Current in Shutdown	VEN1/EN2=0V, VIN=4.2V	-	-	1	∞A
fosc	Each Converter Oscillator Frequency	V _{FB} =0.6V	1.2	1.5	1.8	MHz
fosc_ffb	Each Converter Frequency Foldback	V _{FB} =0V	-	210	-	kHz
RDS-P	Each Converter On Resistance of PMOSFET	Isw=100mA	-	0.28	-	&
Rds-N	Each Converter On Resistance of NMOSFET	Isw=-100mA	-	0.25	_	&
VEN1/EN2	Each Converter Enable Threshold		0.4	-	1	V
Тотр	Thermal Shutdown Threshold		-	150	-	°C
	Thermal Shutdown Hysteresis		-	50	-	°C

Typical Operating Characteristics

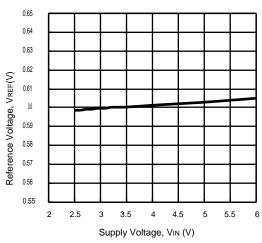
(Refer to the application circuit in the section "Typical Application Circuits", $V_{IN}=3.6V$, $V_{OUT}=1.8V$, $T_A=25$ och unless otherwise specified)

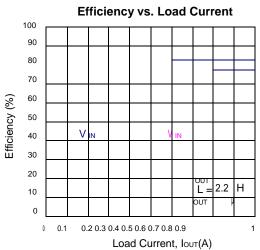


Supply Voltage v.s. Quiescent Current

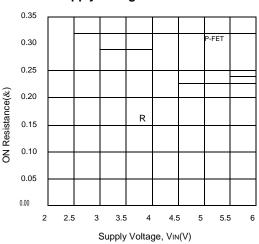


Supply Voltage v.s. Reference Voltage





Supply Voltage vs. ON Resistance



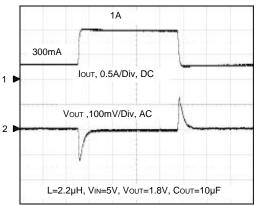
Operating Waveforms

(Refer to the application circuit in the section "Typical Application Circuits", $V_{IN}=3.6V$, $V_{OUT}=1.8V$, $T_A=25$ C unless otherwise specified)

Soft Start Ven Vout ,1V/Div, DC IIN, 200mA/Div L=2.2µH, VIN=5V, Cout=10µF

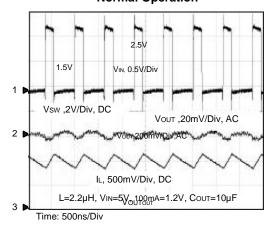
Time: 100µ s/Div

Load Transient Response



Time: 100µ s/Div

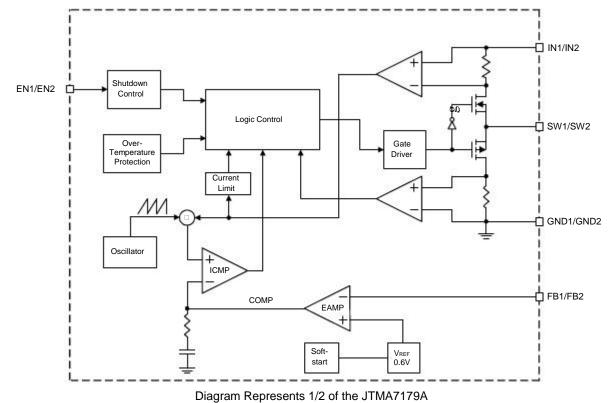
Normal Operation



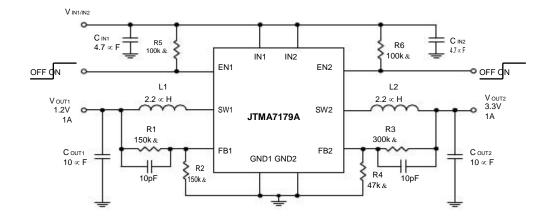
Pin Description

Р	IN	FUNCTION
NO.	NAME	TONOTION
1	IN2	Channel 2 Supply Input. Bypass to the GND2 with a 4.7∞F or greater ceramic capacitor.
2	SW2	Channel 2 Power Switch Output. Inductor connection to drains of the internal PMOSFET and NMOSFET switches.
3	GND2	Ground 2. Connected the exposed pad to the GND2.
4	FB1	Channel 1 Feedback Input. Connect FB1 to the center point of the external resistor divider. The feedback voltage is 0.6V.
5, 11	NC	No Internal Connection.
6	EN1	Channel 1 Enable Control Input. Drive EN1 above 1V to turn on the Channel 1. Drive EN1 below 0.4V to turn it off. In shutdown situation, all functions are disabled to decrease the supply current below 1∞A. Don't left this pin floating.
7	IN1	Channel 1 Supply Input. Bypass to the GND1 with a 4.7∞F or greater ceramic capacitor.
8	SW1	Channel 1 Power Switch Output. Inductor connection to drains of the internal PMOSFET and NMOSFET switches.
9	GND1	Ground 1. Connected the exposed pad to the GND1.
10	FB2	Channel 2 Feedback Input. Connect FB2 to the center point of the external resistor divider. The feedback voltage is 0.6V.
12	EN2	Channel 2 Enable Control Input. Drive EN2 above 1V to turn on the Channel 2. Drive EN2 below 0.4V to turn it off. In shutdown situation, all functions are disabled to decrease the supply current below 1∞A. Don't left this pin floating.
Exposed Pad	NC	No Internal Connection. Connecting this pad to GND1 and GND2.

Block Diagram



Typical Application Circuit



Function Description

Main Control Loop

The JTMA7179A has dual independent constant frequency, current-mode PWM step-down converters. During normal operation, the internal P-channel power MOSFET is turned on each cycle when the oscillator sets an internal RS latch and is turned off when an internal comparator (ICMP) resets the latch. The peak inductor current at which ICMP resets the RS latch is controlled by the voltage on the COMP, which is the output of the error amplifier (EAMP). An external resistive divider connected between Vout and ground allows the EAMP to receive an output feedback voltage VFB at FB pin. When the load current increases, it causes a slightly decrease in VFB associated with the 0.6V reference, which in turn causes the COMP voltage to increase until the average inductor current matches the new load current.

Soft-Start

Each channel in the JTMA7179A has a built-in soft-start to control the output voltage rise during start-up. During soft-start, an internal ramp, connected to the one of the positive inputs of the error amplifier, raise up to replace the reference voltage (0.6V typical) until the ramp voltage reaches the reference voltage.

Short Circuit Protection

For each channel, when the output is shortened to the ground, the frequency of the oscillator will be reduced to 210kHz. This lower frequency allows the inductor current to safely discharge, thereby preventing current runaway. The oscillator's frequency will gradually increase to its designed rate when the feedback voltage on the FB again approaches 0.6V.

Over-Temperature Protection (OTP)

For each channel, the over-temperature circuit limits the junction temperature of the JTMA7179A. When the junction temperature exceeds 150_°C, a thermal sensor turns off the power MOSFETs, allowing the channels to cool down. The thermal sensor allows the converter to start a soft-start process and to regulate the output voltage again after the junction temperature cools by 40_°C. The OTP is designed with a 40_°C hysteresis to lower the average

Junction Temperature (T_J) during continuous thermal overload conditions, increasing the lifetime of the device.

Enable/Shutdown

For each channel, driving EN to the ground places the channel in shutdown mode. When in shutdown, the internal power MOSFETs are turned off, all internal circuitry shuts down, and the quiescent supply current reduces to $1 \propto A$ maximally.

Application Information

Inductor Selection

Due to the high switching frequency as 1.5MHz, the inductor value of the application of the JTMA7179A is usually in the range from $1 \times H$ to $4.7 \times H$. The criterion of selecting a suitable inductor depends on its maximum current ripple. The maximum current ripple defines as 40% of the fully load current. In the JTMA7179A applications, the maximum value of current ripple is 400mA, the 40% of 1A. Calculate L by the equation (1):

$$L = \frac{(V_{\text{IN}} \square V_{\text{OUT}}) \oplus V_{\text{OUT}} \oplus}{V_{\text{IN}}} \frac{1}{\square L \oplus \text{fosc}} \dots (1)$$

where fosc is the switching frequency of JTMA7179A and \Box IL is the value of the maximum current ripple. It can be any value of current ripple that smaller than the maximum value you can accept. In order to perform high efficiency, selecting a low DC resistance inductor is a helpful way. Another important parameter is the DC current rating of the inductor. The minimum value of DC current rating equals the full load value of 1A, and then plus the half of the current ripple. Choose inductors with suitable DC current rating to ensure the inductors don't operate in the saturation.

Input Capacitor Selection

The input capacitor must be able to support the maximum input operating voltage and maximum RMS input current. The Buck converter absorbs pulse current from input power source.

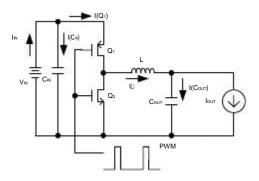
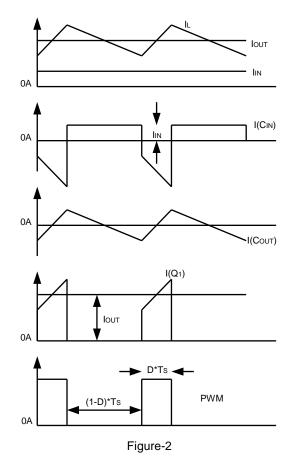


Figure-1

Figure-1 shows a schematic of a Buck converter. The waveforms are shown as Figure-2.



By observing the waveform of $I(C_{\mbox{\tiny IN}})$, the RMS value of $I(C_{\mbox{\tiny IN}})$ is

$$I(C_{IN}) = \sqrt{\left(\left(\frac{2}{100T} - \frac{2}{100T} \right) \left(\frac{2}{100T} \right)^{2} - \frac{2}{100T} \right)^{2}}$$
(2

Replace D and I_{IN} by following relation:

The RMS value of input capacitor current equal:

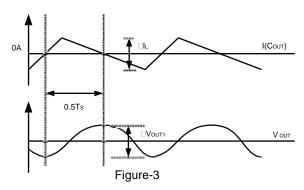
$$I(C_{IN}) = I_{OUT} \oplus D(1/D)....(5)$$

When D=0.5, the RMS current of input capacitor will be maximum value. Use this value to choose the input capacitor with suitable current rating.

Application Information (Cont.)

Output Capacitor Selection

The output voltage ripple is a significant parameter to estimate the performance of a convertor. There are two discrete components that affect the output voltage ripple to be bigger or smaller. It is recommended to use the criterion mentioned in the "Inductor Selection" to choose a suitable inductor. Then, based on this known inductor current ripple, the value and equivalent-series-resistance (ESR) of output capacitor will affect the output voltage ripple to be smaller or larger. The output voltage ripple consists of two portions, one is the product of ESR and inductor current ripple, the other portion is the function of the inductor current ripple and the output capacitance. Figure-3 illustrates the waveform of the ripple voltage which is generated when the inductor ripple current charges or discharges the pure capacitor without the ESR.



Evaluate the $\Box V_{\text{OUT1}}$ by the ideal of energy equalization. According to the definition of Q,

$$Q = \frac{1}{2} \left| \frac{1}{2} \frac{1}{|A|} \right| T_s = C_{OUT} \oplus |V_{OUT}| \dots (6)$$

where T_S is the inverse of switching frequency and the $\Box I_L$ is the inductor current ripple. Move the C_{OUT} to the left side to estimate the value of $\Box V_{OUT1}$ as equation (7).

$$\Box V_{OUT1} = \frac{\Box I_L \oplus T_S}{8 \oplus C_{OUT}} \qquad (7)$$

As mentioned above, one part of output voltage ripple is the product of the inductor current ripple and ESR of output capacitor. The equation (8) explains the output voltage ripple estimation.

$$\Box Vout = \Box IL \oplus \left\{ \left\lceil ESR + \frac{Ts}{8 \oplus Cout} \right\} \right\}....(8)$$

Thermal Consideration

JTMA7179A is a high efficiency switching converter, it means less power loss transferred into heat. Due to the on resistance difference between internal power PMOSFET and NMOSFET, the power dissipation at high duty cycle is greater than the low duty cycle. The worst case in the dropout operation is the conduction loss dissipate mainly on the internal power PMOSFET. The power dissipation is nearly defined as:

$$P_D = \begin{pmatrix} I_D \\ I_D \\ I_D \end{pmatrix} \begin{bmatrix} 2 \\ R_D \\ I_D \\ I_D \end{bmatrix} + R_D \\ I_D \\ I_D \end{bmatrix} + \begin{pmatrix} I_D \\ I_D \\ I_D \end{bmatrix}$$

The JTMA7179A provides internal over-temperature protection. When the junction temperature reaches 150 degrees centigrade, the JTMA7179 will turn off both internal power PMOSFET and NMOSFET. The estimation of the junction temperature, T_J, is defined as:

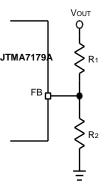
$$T_J = P_D \oplus \setminus_{JA}$$
 (10)

where the \bigcup_A is the thermal resistance of the package utilized by the JTMA7179A.

Output Voltage Setting

Then JTMA7179A has the adjustable version for output voltage setting by the users. A suggestion of maximum value of R_2 is 300k& to keep the minimum current that provides enough noise rejection ability through the resistor divider. The output voltage is programmed by the equation as below:

$$V_{OUT} = 0.6 \oplus \left[\sqrt{1 + \frac{R_1}{R_2}} \right]$$
 (11)



Application Information (Cont.)

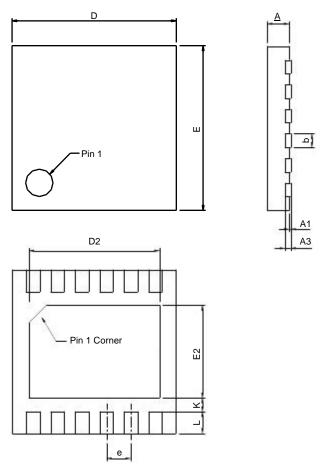
Layout Consideration

For all switching power supplies, the layout is an important step in the design; especially at high peak currents and switching frequencies. If the layout is not carefully done, the regulator might show noise problems and duty cycle jitter.

- The input capacitor should be placed close to the VIN and the GND. Connecting the capacitor and VIN/GND with short and wide trace without any via holes for good input voltage filtering.
- The high current paths (GND1/GND2, IN1/IN2, and SW1/ SW2) should be placed very close to the device with short, direct and wide traces.
- To minimize copper trace connections that can inject noise into the system, the inductor should be placed as close as possible to the SW pin to minimize the noise coupling into other circuits.
- 4. Since the feedback pin and network is a high impedance circuit, the feedback network should be routed away from the inductor. The feedback pin and feedback network should be shielded with a ground plane or trace to minimize noise coupling into this circuit.
- 5. A star ground connection or ground plane minimizes ground shifts and noise is recommended.

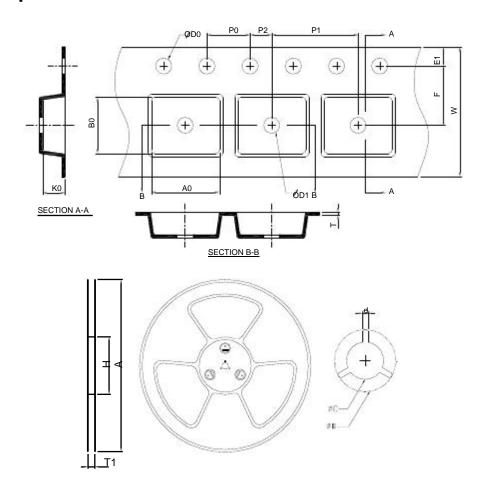
Package Information

TDFN3x3-12



s		TDFN3	x3-12	
S Y M B O L	MILLIMETERS		INCH	HES
Ď	MIN.	MAX.	MIN.	MAX.
Α	0.70	0.80	0.028	0.031
A1	0.00	0.05	0.000	0.002
А3	0.20 REF		0.008	REF
b	0.18	0.30	0.007	0.012
D	2.90	3.10	0.114	0.122
D2	2.20	2.70	0.087	0.106
Е	2.90	3.10	0.114	0.122
E2	1.40	1.75	0.055	0.069
е	0.45 BSC		0.018	BSC
L	0.30	0.50	0.012	0.020
K	0.20		0.008	

Carrier Tape & Reel Dimensions



Application	Α	Н	T1	С	d	D	W	E1	F
TDENO. 0.10	330±2.00	50 MIN.	12.4+2.00 -0.00	13.0+0.50 -0.20	1.5 MIN.	20.2 MIN.	12.0±0.30	1.75±0.10	5.5±0.05
TDFN3x3-12	P0	P1	P2	D0	D1	Т	A0	В0	K0
				1.5+0.10		0.6+0.00			

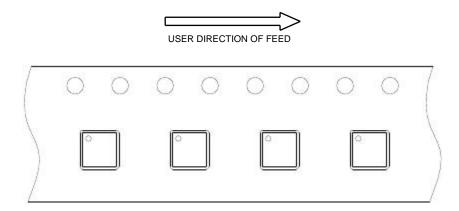
(mm)

Devices Per Unit

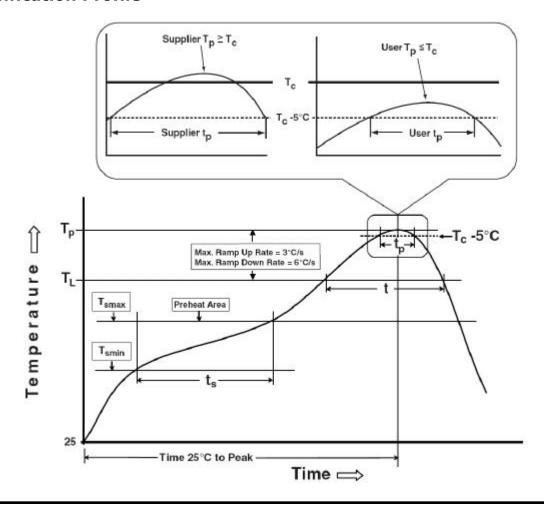
Package Type	Unit	Quantity	
TDFN3x3-12	Tape & Reel	3000	

Taping Direction Information

TDFN3x3-12



Classification Profile



Classification Reflow Profiles

Profile Feature	Sn-Pb Eutectic Assembly	Pb-Free Assembly
Preheat & Soak Temperature min (Tsmin) Temperature max (Tsmax) Time (Tsmin to Tsmax) (ts)	100 °C 150 °C 60-120 seconds	150 °C 200 °C 60-120 seconds
Average ramp-up rate (Tsmax to TP)	3 °C/second max.	3°C/second max.
Liquidous temperature (TL) Time at liquidous (tL)	183 °C 60-150 seconds	217 °C 60-150 seconds
Peak package body Temperature (T _p)*	See Classification Temp in table 1	See Classification Temp in table 2
Time (tp)** within 5°C of the specified classification temperature (Tc)	20** seconds	30** seconds
Average ramp-down rate (Tp to Tsmax)	6 °C/second max.	6 °C/second max.
Time 25°C to peak temperature	6 minutes max.	8 minutes max.

^{*} Tolerance for peak profile Temperature (Tp) is defined as a supplier minimum and a user maximum.

Table 1. SnPb Eutectic Process – Classification Temperatures (Tc)

Package Thickness	Volume mm ³ <350	Volume mm ³ ε350
<2.5 mm	235 °C	220 °C
ε2.5 mm	220 °C	220 °C

Table 2. Pb-free Process – Classification Temperatures (Tc)

Package Thickness	Volume mm ³ <350	Volume mm ³ 350-2000	Volume mm ³ >2000
<1.6 mm	260 °C	260 °C	260 °C
1.6 mm – 2.5 mm	260 °C	250 °C	245 °C
ε2.5 mm	250 °C	245 °C	245 °C

Reliability Test Program

Test item	Method	Description
SOLDERABILITY	JESD-22, B102	5 Sec, 245°C
HOLT	JESD-22, A108	1000 Hrs, Bias @ T _j =125°C
PCT	JESD-22, A102	168 Hrs, 100%RH, 2atm, 121°C
TCT	JESD-22, A104	500 Cycles, -65°C~150°C
НВМ	MIL-STD-883-3015.7	VHBM≧2KV
MM	JESD-22, A115	VMM≧200V
Latch-Up	JESD 78	10ms, 1tr≧100mA

^{**} Tolerance for time at peak profile temperature (tp) is defined as a supplier minimum and a user maximum.

Customer Service